DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 May 25 2002 Jan 23



Product specification

1N4148; 1N4448

FEATURES

- Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 4 ns
- General application
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 100 V
- Repetitive peak forward current: max. 450 mA.

APPLICATIONS

• High-speed switching.

LIMITING VALUES

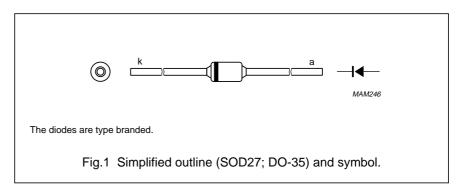
In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage		-	100	V
V _R	continuous reverse voltage		-	75	V
I _F	continuous forward current	see Fig.2; note 1	-	200	mA
I _{FRM}	repetitive peak forward current		-	450	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	4	А
		t = 1 ms	_	1	А
		t = 1 s	-	0.5	A
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	-	500	mW
T _{stg}	storage temperature		-65	+200	°C
Tj	junction temperature		-	200	°C

Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

The 1N4148 and 1N4448 are high-speed switching diodes fabricated in planar technology, and encapsulated in hermetically sealed leaded glass SOD27 (DO-35) packages.



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ELECTRICAL CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	see Fig.3			
	1N4148	I _F = 10 mA	_	1	V
	1N4448	I _F = 5 mA	0.62	0.72	V
		I _F = 100 mA	_	1	V
I _R	reverse current	V _R = 20 V; see Fig.5		25	nA
		$V_R = 20 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ see Fig.5}$	_	50	μA
I _R	reverse current; 1N4448	V _R = 20 V; T _j = 100 °C; see Fig.5	_	3	μA
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	-	4	pF
t _{rr}	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 60$ mA; $R_L = 100 \Omega$; measured at $I_R = 1$ mA; see Fig.7	-	4	ns
V _{fr}	forward recovery voltage	when switched from $I_F = 50$ mA; $t_r = 20$ ns; see Fig.8	_	2.5	V

THERMAL CHARACTERISTICS

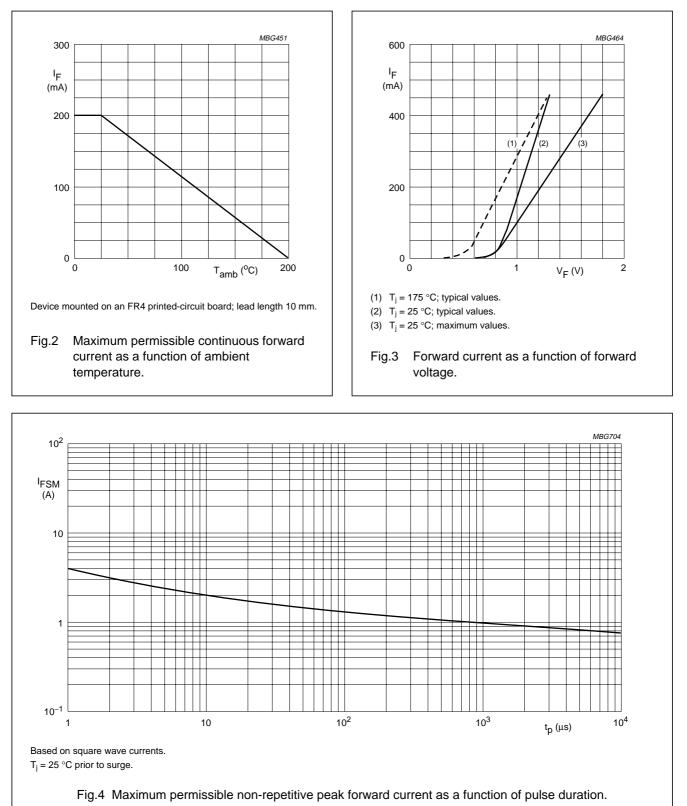
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
R _{th j-a}	thermal resistance from junction to ambient	lead length 10 mm; note 1	350	K/W

Note

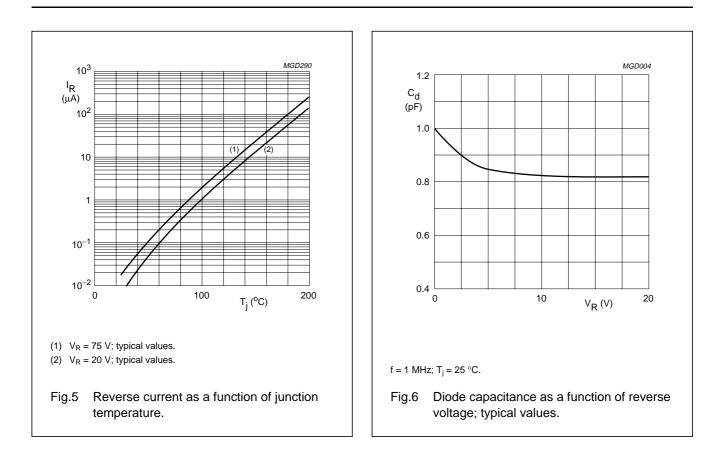
1. Device mounted on a printed circuit-board without metallization pad.

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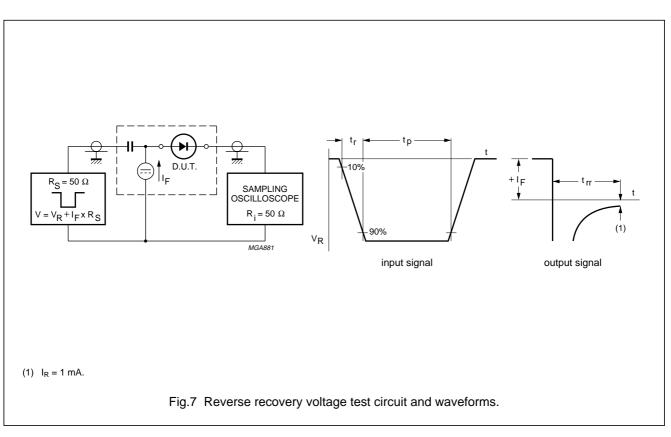
GRAPHICAL DATA

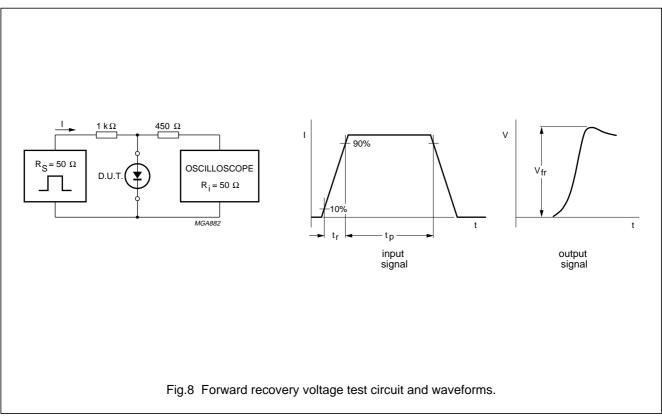


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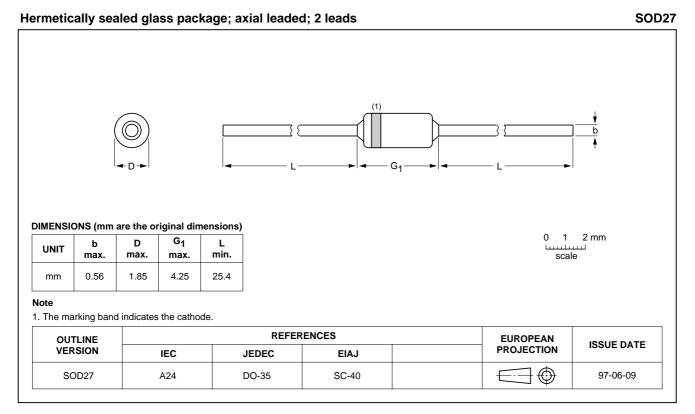
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PACKAGE OUTLINE



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DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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